

## **FED'13**

## Functionality-Enhanced Devices Workshop EPFL, Lausanne, Switzerland

25 March 2013

9:00 - 10:00 PART I: Silicon-based Controllable Polarity Devices Fabrication

"Reconfigurable Nanowire Electronics - Device Principles and Prospects"

Walter Weber, Namlab, Dresden, Germany

"Polarity Control at the Runtime in Double-Gate, Gate-All-Around Vertically Stacked Silicon

Nanowire FETs"

Michele De Marchi, EPFL, Lausanne, Switzerland

10:00 - 10:30 Coffee Break

10:30 - 12:00 PART II: Carbon-based and Carbon-like Materials, Devices and Circuits

"MoS<sub>2</sub> Based Devices and Circuits"

Andras Kis, EPFL, Lausanne, Switzerland

"Electrostatically-Reversible Polarity of Dual-Gated Graphene Transistors"

Shu Nakaharai, AIST, Japan

"Electrostatic Doping in Carbon-based Nanoelectronics Devices"

Joachim Knoch, RWTH Aachen, Germany

"Sacha, the Stanford Carbon Nanotube Controlled Handshaking Robot"

Max Shulaker, Stanford University, California, USA

12:00 - 14:00 Lunch

14:00 - 15:30 PART III: Compact Modeling and Circuit Design

"Compact Model for Multiple Independent Gates Ambipolar Devices"

Gianluca Piccini, Politecnico di Torino, Torino, Italy

"Ambipolar Logic Circuit Design and Synthesis"

lan O'Connor, Institute of Nanotechnologies of Lyon, Ecully, France

"Specific Design Techniques for Controllable Ambipolar Transistors: from Physical Design to Circuit Simulation"

Haykel Ben Jamaa, CEA, LETI, Minatec Campus, Grenoble, France

"Layout Technique for Double-Gate Silicon Nanowire FETs with an Efficient Sea-of-Tiles Architecture"

Shashi Bobba, EPFL, Lausanne, Switzerland

15:30 - 16:00 Coffee Break

16:00 - 17:15 PART IV: Advanced Architectural Design

"Modularity Study of Ultra-fine Grain Reconfigurable Architectures Based on DG-CNTFET" Fabien Clermidy, CEA, LETI, Minatec Campus, Grenoble, France

"Biconditional BDD: A Novel Canonical BDD Enabling Efficient Direct Mapping of DG Controllable Polarity FETs"

Luca Amaru, EPFL, Lausanne, Switzerland

"Auto-Reconfiguration in Statically Interconnected CNTFET-based Cells" Sébastien Le Beux, Institute of Nanotechnologies of Lyon, Ecully, France

17:15 - 17:45 Concluding Discussions